



# LC66P308

## 4-bit Microcontroller with Built-in PROM

### Overview

The LC66P308 is a 4-bit microcontroller with a built-in 8 Kbyte PROM. It is compatible with the LC663XX series mask ROM devices, making it ideal for prototyping and software development and testing.

The LC66P308 features 33 user-defined options comprising output configuration, output level after reset, watchdog timer and oscillator configuration options. The output configuration options are open-drain, open-drain with pull-up, and CMOS. The oscillator options are ceramic resonator, RC oscillator and external clock.

The LC66P308 operates from a 5 V supply and is available in 42-pin DIPs and 48-pin QIPs.

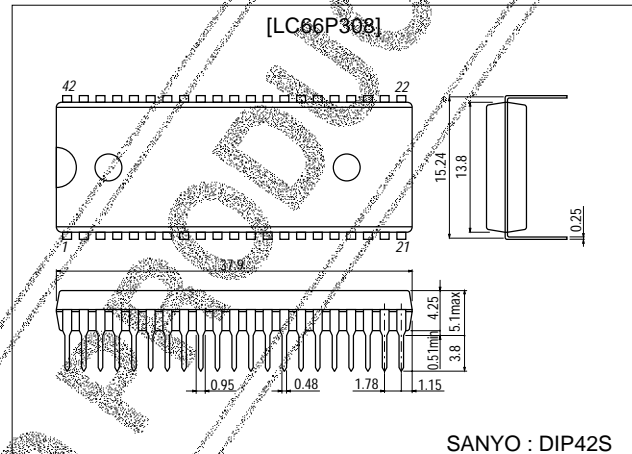
### Features

- 33 user-defined options including port output configuration, output level after reset and watchdog timer options
- Ceramic resonator, RC oscillator or external clock option
- 8 Kbyte PRQM (0000H to 2007H user addressable)
- Compatible with the LC663XX series mask ROM devices
- 0.92 to 10.0  $\mu$ s instruction cycle time
- 5 V supply
- 42-pin DIP and 48-pin QIP

### Package Dimensions

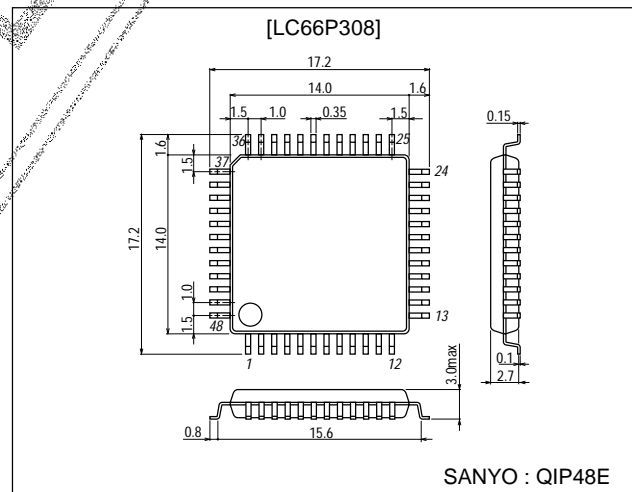
Unit:mm

3025B-DIP42S



Unit:mm

3156-QIP48E



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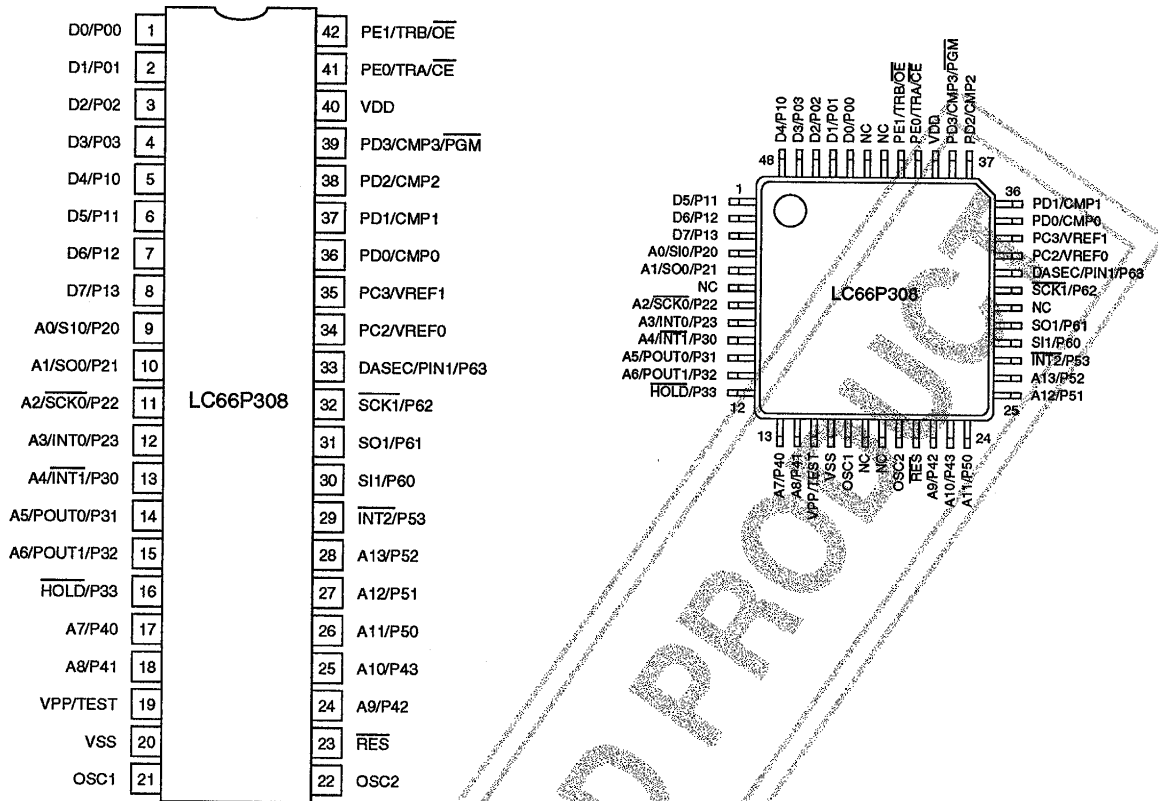
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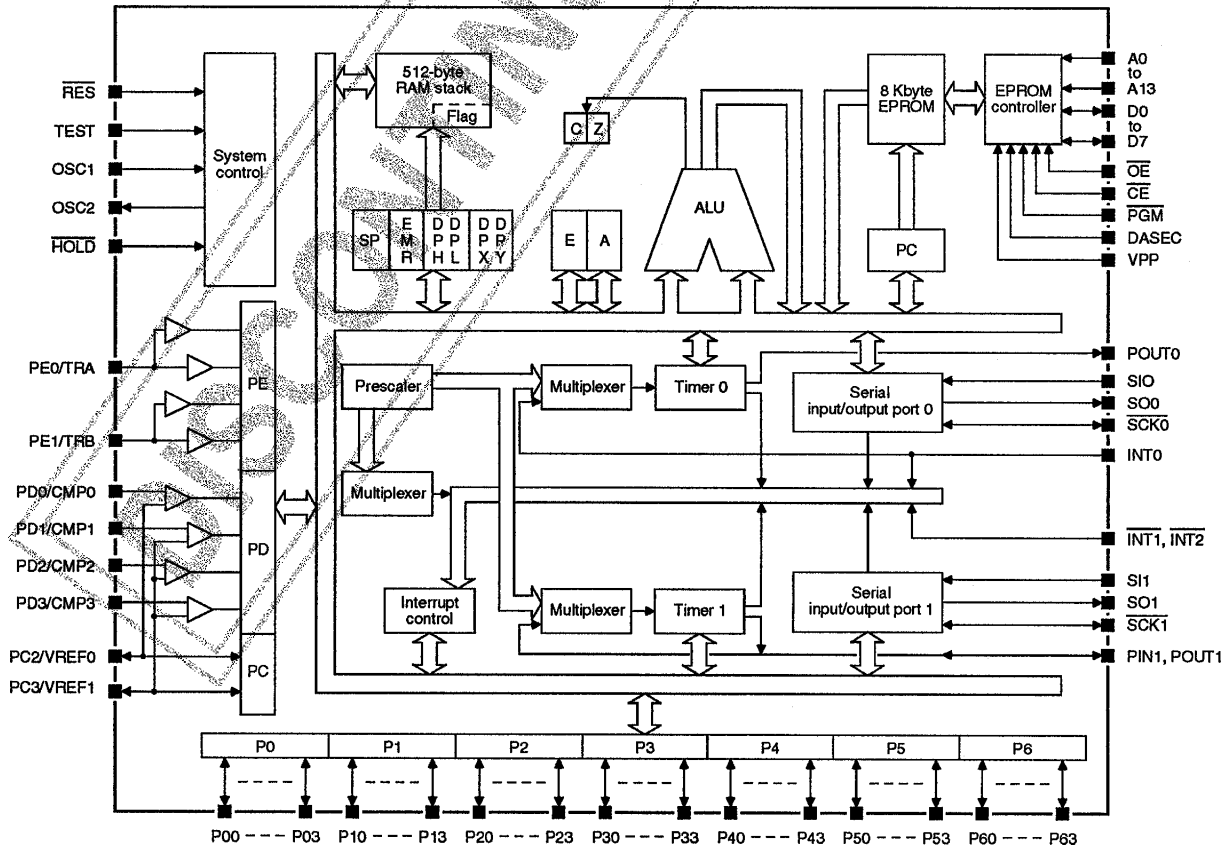
# LC66P308

## Pin Assignment



Top view

## Block Diagram



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## Pin Description

Number		Name	Description
DIP42S	DIP48E		
1	44	D0/P00	Multiplexed 4-bit input/output port P0 (P00 to P03) and PROM data bus lines (D0 to D3)
2	45	D1/P01	
3	46	D2/P02	
4	47	D3/P03	
5	48	D4/P10	Multiplexed 4-bit input/output port P1 (P10 to P13) and PROM data bus lines (D4 to D7)
6	1	D5/P11	
7	2	D6/P12	
8	3	D7/P13	
9	4	A0/SI0/P20	Multiplexed 4-bit input/output port P2 (P20 to P23), serial input 0 (SI0), serial output 0 (SO0), serial clock 0 (SCK0), interrupt request 0 (INT0) and PROM address bus lines (A0 to A3)
10	5	A1/SO0/P21	
11	7	A2/SCK0/P22	
12	8	A3/INT0/P23	
13	9	A4/INT1/P30	Multiplexed 3-bit input/output port P3 (P30 to P32), interrupt request 1 (INT1), timer outputs (POUT0 and POUT1) and address bus lines (A4 to A6) multiplexed single-bit input port (P33) and hold-mode control input (HOLD)
14	10	A5/POUT0/P31	
15	11	A6/ROUT1/P32	
16	12	HOLD/P33	
17	13	A7/P40	Multiplexed 4-bit input/output port P4 (P40 to P43) and PROM address bus lines (A7 to A10)
18	14	A8/P41	
24	22	A9/P42	
25	23	A10/P43	
19	15	VPP/TEST	CPU test input
20	16	VSS	Ground
21	17	OSC1	External oscillator connections
22	20	OSC2	
23	21	RES	Reset input
26	24	A11/P50	Multiplexed 4-bit input/output port P5 (P50 to P53), interrupt request 2 (INT2) and PROM address bus lines (A11 to A13)
27	25	A12/P51	
28	26	A13/P52	
29	27	INT2/P53	
30	28	SI1/P60	Multiplexed 4-bit input/output port P6 (P60 to P63), serial input 1 (SI1), serial output 1 (SO1), serial clock 1 (SCK1), event counter input (PIN1) and PROM data security control input (DASEC)
31	29	SO1/P61	
32	31	SCK1/P62	
33	32	DASEC/PIN1/P63	
34	33	PC2/VREF0	Multiplexed 2-bit input/output port PC (PC2 and PC3), CMP0 reference voltage input (VREF0) and CMP1 to CMP3 reference voltage input (VREF1)
35	34	PC3/VREF1	
36	35	PD0/CMP0	Multiplexed 4-bit input port PD (PD0 to PD3), PROM program control input (PGM) and comparator inputs (CMP0 to CMP3)
37	36	PD1/CMP1	
38	37	PD2/CMP2	
39	38	PD3/CMP3/PGM	
40	39	VDD	5V supply
41	40	PE0/TRA/CE	Multiplexed 2-bit input port PE (PE0 and PE1), 2-bit three-level input port (TRA and TRB), PROM chip enable (CE) and output enable (OE)
42	41	PE1/TRB/OE	
	6, 18, 19, 30, 42, 43	NC	No connection

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## Specifications

**Absolute Maximum Ratings** at  $T_a = 25^\circ\text{C}$ ,  $V_{SS} = 0\text{V}$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	$V_{DD}$		-0.3 to +7.0	V
Ports P2 to P6 (excluding P33) input voltage	$V_{I1}$	See note 1	-0.3 to +15.0	V
Input voltage range for all inputs	$V_{I2}$	See note 2	-0.3 to $V_{DD}+0.3$	V
Ports P2 to P6 (excluding P33) output voltage	$V_{O1}$	See note 1	-0.3 to +15.0	V
Output voltage range for all outputs	$V_{O2}$	See note 2	-0.3 to $V_{DD}+0.3$	V
Ports P0, P1, P4 and P5 output source current	$-I_{OP1}$		2	mA
Ports P2, P3 (excluding P33), P6 and PC output source current	$-I_{OP2}$		4	mA
Ports P0 to P6 (excluding P33) and PC output sink current	$I_{ON}$		20	mA
Ports P0 to P3 (excluding P33), P40 and P41 total sink current	$\Sigma I_{ON1}$		75	mA
Ports P42, P43, P5, P6 and PC total sink current	$\Sigma I_{ON2}$		75	mA
Ports P0 to P3 (excluding P33), P40 and P41 total source current	$-\Sigma I_{OP1}$		25	mA
Ports P42, P43, P5, P6 and PC total source current	$-\Sigma I_{OP2}$		25	mA
Power dissipation (DIP42S)	$P_{D1}$		600	mW
Power dissipation (QIP48E)	$P_{D2}$	See note 3	430	mW
Operating temperature range	$T_{opr}$		-30 to +70	$^\circ\text{C}$
Storage temperature range	$T_{stg}$		-55 to +125	$^\circ\text{C}$

### Notes

1. Open-drain output configuration option
2. All output configuration options
3. Heat-soak the QIP package before mounting. Do not immerse the package in the solder dip tank when mounting the QIP on the substrate, and avoid prolonged contact with the solder.

**Recommended Operating Conditions** at  $T_a = 25^\circ\text{C}$ ,  $V_{SS} = 0\text{V}$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	$V_{DD}$		5	V
Supply voltage range	$V_{DD}$		4.5 to 5.5	V
Hold-mode supply voltage range for data retention	$V_{DD}$		1.8 to 5.5	V

**Electrical Characteristics** at  $T_a = -30$  to  $+70^\circ\text{C}$ ,  $V_{DD} = 4.5$  to  $5.5\text{V}$ ,  $V_{SS} = 0\text{V}$ , unless otherwise noted

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Reset-mode supply current	$I_{DD}$	4MHz ceramic resonator		4.5	8.0	mA
		4MHz external clock		6.5	11.0	mA
		RC oscillator		4	8	mA
Halt-mode supply current	$I_{DDHT}$	4MHz ceramic resonator		3.0	5.0	mA
		4MHz external clock		3.5	6.0	mA
		RC oscillator		3.0	5.0	mA
Hold-mode supply current	$I_{DDHD}$	$V_{DD} = 1.8$ to $5.5\text{V}$		0.01	10.0	$\mu\text{A}$
Ports P2, P3 (excluding P33), P5 and P6, RES and OSC1 LOW-level input voltage	$V_{IL1}$	Output n-channel transistor OFF. See note 1.	$V_{SS}$		$0.25V_{DD}$	V
HOLD/P33 LOW-level input voltage	$V_{IL2}$	$V_{DD} = 1.8$ to $5.5\text{V}$	$V_{SS}$		$0.25V_{DD}$	V
Ports P0, P1, P4 PC, PD and PE, and TEST LOW-level input voltage	$V_{IL3}$	Output n-channel transistor OFF. See note 1.	$V_{SS}$		$0.3V_{DD}$	V
Ports PE LOW-level input voltage	$V_{IL4}$	Ternary input mode.	$V_{SS}$		$0.2V_{DD}$	V
Ports PE MID-level input voltage	$V_{IM}$	Ternary input mode.	$0.4V_{DD}$		$0.6V_{DD}$	V
Ports P2 to P6 (excluding P33) HIGH-level input voltage	$V_{IH1}$	Output n-channel transistor OFF. See note 2.	$0.75V_{DD}$		13.5	V
HOLD/P33, RES and OSC1 HIGH-level input voltage	$V_{IH2}$	Output n-channel transistor OFF	$0.75V_{DD}$		$V_{DD}$	V
Ports P0, P1, PC, PD and PE HIGH-level input voltage	$V_{IH3}$	Output n-channel transistor OFF. See note 1.	$0.7V_{DD}$		$V_{DD}$	V
Port PE HIGH-level input voltage	$V_{IH4}$	Ternary input mode.	$0.8V_{DD}$		$V_{DD}$	V

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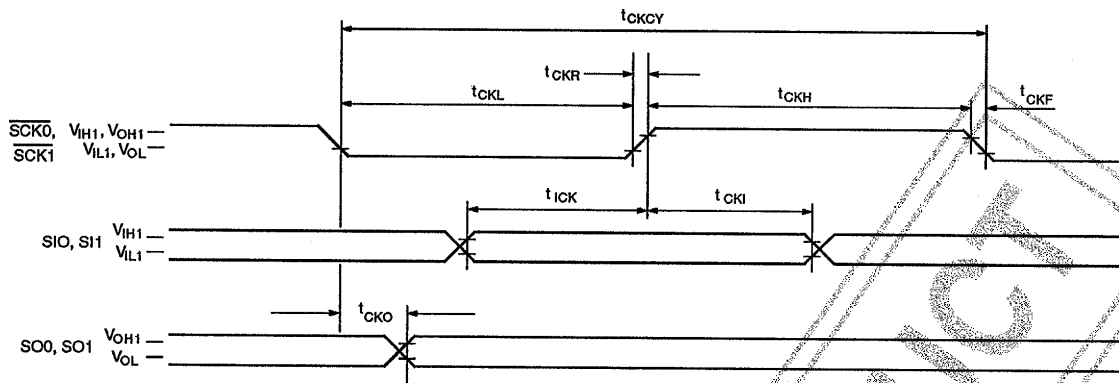
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Ports P0 to P6 (excluding P33) and PC LOW-level output voltage	$V_{OL}$	$I_{OL}=1.6\text{mA}$			0.4	V
		$I_{OL}=10\text{mA}$			1.5	V
Ports P2, P3 (excluding P33), P6 and PC HIGH-level output voltage	$V_{OH1}$	$I_{OH}=-1\text{mA}$ . See note 3.	$V_{DD}-1.0$			V
		$I_{OH}=-0.1\text{mA}$ . See note 3.	$V_{DD}-0.5$			V
Ports P0, P1, P4 and P5 HIGH-level output voltage	$V_{OH2}$	$V_{DD}=4.5\text{V}$ , $I_{OH}=-0.2\text{mA}$ . See note 4.	2.4			V
		$I_{OH}=-0.13\text{mA}$ . See note 4.	$V_{DD}-1.35$			V
Ports PC and PD in-phase, comparator input voltage	$V_{CMM}$		1.0		$V_{DD}-1.5$	V
Port PD comparator offset voltage	$V_{OFF}$	$V_I=1.0$ to $V_{DD}-1.5\text{V}$		$\pm 50$	$\pm 300$	mV
Ports P2, P3, P5 and P6, and $\overline{RES}$ and OSC1 Schmitt-trigger LOW-level threshold voltage	$V_{tL}$		$0.25V_{DD}$		$0.5V_{DD}$	V
Ports P2, P3, P5 and P6, and $\overline{RES}$ and OSC1 Schmitt-trigger HIGH-level threshold voltage	$V_{tH}$		$0.5V_{DD}$		$0.75V_{DD}$	V
Ports P2, P3, P5 and P6, $\overline{RES}$ and OSC1 Schmitt-trigger hysteresis voltage	$V_{HYS}$			$0.1V_{DD}$		V
LOW-level input current for all inputs	$I_{iL}$	$V_I=V_{SS}$ , output n-channel transistor OFF. See note 2	-1			$\mu\text{A}$
Ports P2 to P6 (excluding P33) HIGH-level input current	$I_{iH1}$	$V_I=13.5\text{V}$ , output n-channel transistor OFF. See note 2			5	$\mu\text{A}$
Ports P0, P1 and P33, and $\overline{RES}$ and OSC1 HIGH-level input current	$I_{iH2}$	$V_I=V_{DD}$ , output n-channel transistor OFF. See note 1			1	$\mu\text{A}$
Ports PC2, PC3, PD and PE HIGH-level input current	$I_{iH3}$	$V_I=V_{DD}$ , output n-channel transistor OFF. See note 1			1	$\mu\text{A}$
Ports P2 to P6 output leakage current	$I_{OFF1}$	$V_I=13.5\text{V}$ . See note 2.			5	$\mu\text{A}$
Ports P0, P1 and PC output leakage current	$I_{OFF2}$	$V_I=V_{DD}$ . See note 2.			1	$\mu\text{A}$
Ports P0, P1, P4 and P5 output current with pull-up option	$I_{PO}$	$V_I=V_{SS}$ , $V_{DD}=5.5\text{V}$ . See note 4.	-1.6			mA
Ceramic resonator input frequency	$f_{CF}$	4MHz resonator		4		MHz
Ceramic resonator input stabilization time	$f_{CFS}$	4MHz resonator			10	ms
RC oscillator input frequency	$f_{RC}$	$R=2.2\text{k}\Omega\pm 1\%$ , $C=100\text{pF}\pm 5\%$	2	3	4	MHz
External RC oscillator capacitance	$C_{ext}$			100		pF
External RC oscillator resistance	$R_{ext}$			2.2		$\text{k}\Omega$

## Notes

1. Ports with CMOS output configuration option cannot be used as input ports.
2. Open-drain output configuration option
3. CMOS output configuration option
4. Pull-up output configuration option

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## Timing Characteristics Serial input/output timing

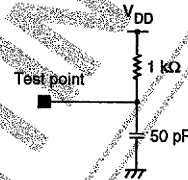


$T_a = -30$  to  $+70$  °C,  $V_{DD} = 4.5$  to  $5.5$  V,  $V_{SS} = 0$  V

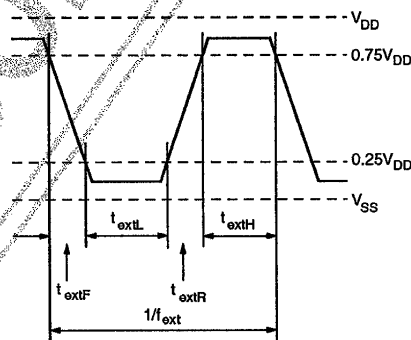
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Instruction cycle time	$t_{CYC}$		0.92		10	$\mu$ s
SCK0 and SCK1 serial clock input cycle time	$t_{CKCY}$		0.9			$\mu$ s
SCK0 and SCK1 serial clock output cycle time	$t_{OCY}$		$2t_{CYC}$			$\mu$ s
SCK0 and SCK1 serial clock input pulsewidth	$t_{CKL}$		0.4			$\mu$ s
SCK0 and SCK1 serial clock output pulsewidth	$t_{CKH}$		$t_{CYC}$			$\mu$ s
SCK0 and SCK1 serial clock output rise time	$t_{CKR}$				0.1	$\mu$ s
SCK0 and SCK1 serial clock output fall time	$t_{CKF}$				0.1	$\mu$ s
SI0 and SI1 serial data setup time	$t_{ICK}$		0.3			$\mu$ s
SI0 and SI1 serial data hold time	$t_{CKI}$		0.3			$\mu$ s
SO0 and SO1 serial data output delay	$t_{CKO}$				0.3	$\mu$ s

### Note

Each test input and output has an RC load as shown in the following figure.



## External clock timing

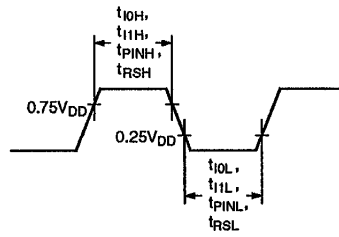


$T_a = -30$  to  $+70$  °C,  $V_{DD} = 4.5$  to  $5.5$  V,  $V_{SS} = 0$  V

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
OSC1 external clock input frequency	$f_{ext}$		0.4		4.35	MHz
OSC1 external clock LOW-level input pulsewidth	$f_{extL}$		70			ns
OSC1 external clock HIGH-level input pulsewidth	$f_{extH}$		70			ns
OSC1 external clock input rise time	$f_{extR}$				30	ns
OSC1 external clock input fall time	$f_{extF}$				30	ns

# LC66P308

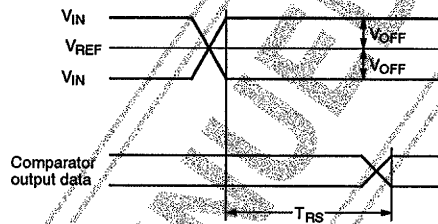
## Interrupt and reset timing



$T_a = -30$  to  $+70$  °C,  $V_{DD} = 4.5$  to  $5.5$  V,  $V_{SS} = 0$  V

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
INT0 LOW-level pulsewidth	$t_{I0L}$		2t <sub>CYC</sub>			μs
INT0 HIGH-level pulsewidth	$t_{I0H}$		2t <sub>CYC</sub>			μs
INT1 and INT2 LOW-level pulsewidth	$t_{I1L}$		2t <sub>CYC</sub>			μs
INT1 and INT2 HIGH-level pulsewidth	$t_{I1H}$		2t <sub>CYC</sub>			μs
PIN1 LOW-level input pulsewidth	$t_{PINL}$		2t <sub>CYC</sub>			μs
PIN1 HIGH-level input pulsewidth	$t_{PINH}$		2t <sub>CYC</sub>			μs
$\overline{RES}$ LOW-level input pulsewidth	$t_{RSL}$		3t <sub>CYC</sub>			μs
$\overline{RES}$ HIGH-level input pulsewidth	$t_{RSH}$		3t <sub>CYC</sub>			μs

## Comparator timing



$T_a = -30$  to  $+70$  °C,  $V_{DD} = 4.5$  to  $5.5$  V,  $V_{SS} = 0$  V

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Port PD comparator response time	$t_{RS}$				30	μs

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## Input and Output Functions

The LC66P308 has many multiplexed pins whose function is controlled by software. The function of each of these pins is shown in the following table.

Name	Function
D0/P00	Ports P00 to P03 can be addressed as either a 4-bit port or four, single-bit ports. They function as data bus lines when memory is addressed. They also have halt-mode control functions. Level after reset is set by user option.
D1/P01	
D2/P02	
D3/P03	
D4/P10	Ports P10 to P13 can be addressed as either a 4-bit port or four, single-bit ports. They function as data bus lines when memory is addressed. Level after reset is set by user option.
D5/P11	
D6/P12	
D7/P13	
A0/SIO/P20	Ports P20 to P23 can be addressed as either a 4-bit port or four, single-bit ports. They function as address bus inputs when memory is addressed. Port P20 also functions as a serial data input, P21 as a serial data output, P22 as a serial data clock and P23 as an interrupt request, pulsewidth measurement and event counter input using timer 0.
A1/SO0/P21	
A2/SCK0/P22	
A3/INT0/P23	
A4/INT1/P30	Ports P30 to P32 can be addressed as either a 3-bit port, a 4-bit port with P33 or three, single-bit ports. They function as address bus inputs when memory is addressed. Port P30 also functions as an interrupt request input, P31 as a square-wave output from timer 0 and P32 as a square-wave output from timer 1 and a PWM output.
A5/POUT0/P31	
A6/POUT1/P32	
HOLD/P33	
A7/P40	Ports P40 to P43 can be addressed as either a 4-bit port, four, single-bit ports or an 8-bit port with P50 to P53. They function as address bus inputs when memory is addressed.
A8/P41	
A9/P42	
A10/P43	
A11/P50	Ports P50 to P53 can be addressed as either a 4-bit port, four, single-bit ports or an 8-bit port with P40 to P43. Ports P50 to P52 function as address bus inputs when memory is addressed. Port P53 also functions as an interrupt request input.
A12/P51	
A13/P52	
INT2/P53	
SI1/P60	Ports P60 to P63 can be addressed as either a 4-bit port or four, single-bit ports. Port P60 also functions as a serial data input, P61 as a serial data output, P62 as a serial data clock and P63 as a data security control input and timer 1 event counter input.
SO1/P61	
SCK1/P62	
DASEC/PIN1/P63	
PC2/VREF0	Ports PC2 and PC3 can be addressed as either a 2-bit port or two, single-bit ports. In addition, Port PC2 also functions as the PD0 reference voltage input, and PC3 as the PD1 to PD3 reference voltage input.
PC3/VREF1	
PD0/CMP0	Ports PD0 to PD3 can be addressed as either a 4-bit port or four, single-bit ports. They also function as comparator inputs. In addition, port PD3 also functions as the memory program control input.
PD1/CMP1	
PD2/CMP2	
PD3/CMP3/BGM	
PE0/TRB/CE	Ports PE0 to PE1 can be addressed as either a 2-bit port or two, single-bit ports. They function as chip enable and write enable, respectively, when memory is addressed. They also function as three-level inputs.
PE1/TRB/OE	
OSC1	OSC1 and OSC2 function as the external ceramic resonator or RC oscillator connections. When an external clock is used, OSC2 is left open.
OSC2	
RES	When $\overline{\text{RES}}$ goes LOW while $\overline{\text{HOLD/P33}}$ is HIGH, the CPU is reset.
VPP/TEST	CPU test input. Normally connected to ground.



**User Options**

**Oscillator Options**

There are three user options for the oscillator—an external clock, an RC oscillator and a ceramic resonator. The internal circuits of OSC1 and OSC2 for the external clock, RC oscillator and ceramic resonator options are shown in figures 1, 2 and 3, respectively. Note the Schmitt-trigger inputs for both the external clock and RC oscillator options.



Figure 1. External clock option

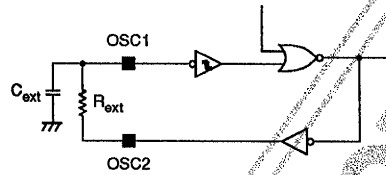


Figure 2. RC oscillator option

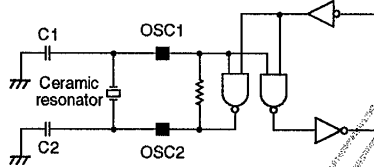


Figure 3. Ceramic resonator option

**Output Options**

There are two user options for the output configuration of each port—n-channel open drain and p-channel, active pull-up, shown in figures 4 and 5, respectively. Ports P2, P3, P5 and P6 have Schmitt-trigger inputs in both output configurations.

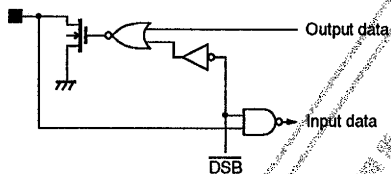


Figure 4. N-channel open-drain option

The p-channel pull-up option for ports P0, P1, P4 and P5 results in an n-channel sink transistor with a p-channel, active pull-up transistor configuration, and for ports P2, P3, P6 and PC, a CMOS configuration.

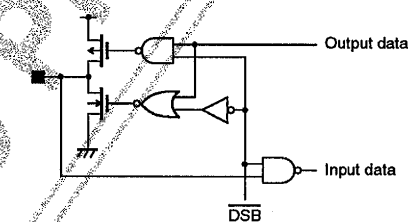


Figure 5. P-channel pull-up option

The n-channel open-drain outputs for ports P2 to P6 have a withstand voltage greater than 15 V.

**Output Level After Reset Option**

The output level of ports P0 and P1 after a CPU reset is user selectable.

**Watchdog Timer Option**

A watchdog timer is available to prevent program run-away.

# LC66P308

## PROM Specification

### Specifying Programs and Options

The user-addressable memory is 0000H to 2007H. Addresses 0000H to 1FFFH are for user programs, and addresses 2000H to 2007H, for option specification.

Addresses 2008H and above can neither be programmed or read. The option specification is coded using the information shown in the following table.

Address	Data bit	Parameter	Option	
			0	1
2000H	D0	Watchdog timer function	No	Yes
	D1	Port P0 level after reset	LOW	HIGH
	D2	Port P1 level after reset	LOW	HIGH
	D3	No function	Set to 0	
	D4	Oscillator	RC oscillator or external clock	Ceramic resonator
	D5 to D7	No function	Set to 0	
2001H	D0	Port P00 output configuration	Open-drain	Pull-up
	D1	Port P01 output configuration		
	D2	Port P02 output configuration		
	D3	Port P03 output configuration	Open-drain	Pull-up
	D4	Port P10 output configuration		
	D5	Port P11 output configuration		
	D6	Port P12 output configuration		
	D7	Port P13 output configuration		
2002H	D0	Port P20 output configuration	Open-drain	CMOS
	D1	Port P21 output configuration		
	D2	Port P22 output configuration		
	D3	Port P23 output configuration	Open-drain	CMOS
	D4	Port P30 output configuration		
	D5	Port P31 output configuration		
	D6	Port P32 output configuration		
	D7	No function		
2003H	D0	Port P40 output configuration	Open-drain	Pull-up
	D1	Port P41 output configuration		
	D2	Port P42 output configuration		
	D3	Port P43 output configuration	Open-drain	Pull-up
	D4	Port P50 output configuration		
	D5	Port P51 output configuration		
	D6	Port P52 output configuration		
	D7	Port P53 output configuration		
2004H	D0	Port P60 output configuration	Open-drain	CMOS
	D1	Port P61 output configuration		
	D2	Port P62 output configuration		
	D3	Port P63 output configuration	Set to 0	
	D4 to D7	No function	Set to 0	
2005H	D0 to D7	No function	Set to 0	
2006H	D0 to D7	No function	Set to 0	
2007H	D0, D1	No function	Set to 0	
	D2	Port PC2 output configuration	Open-drain	CMOS
	D3	Port PC3 output configuration		
	D4 to D7	No function	Set to 0	

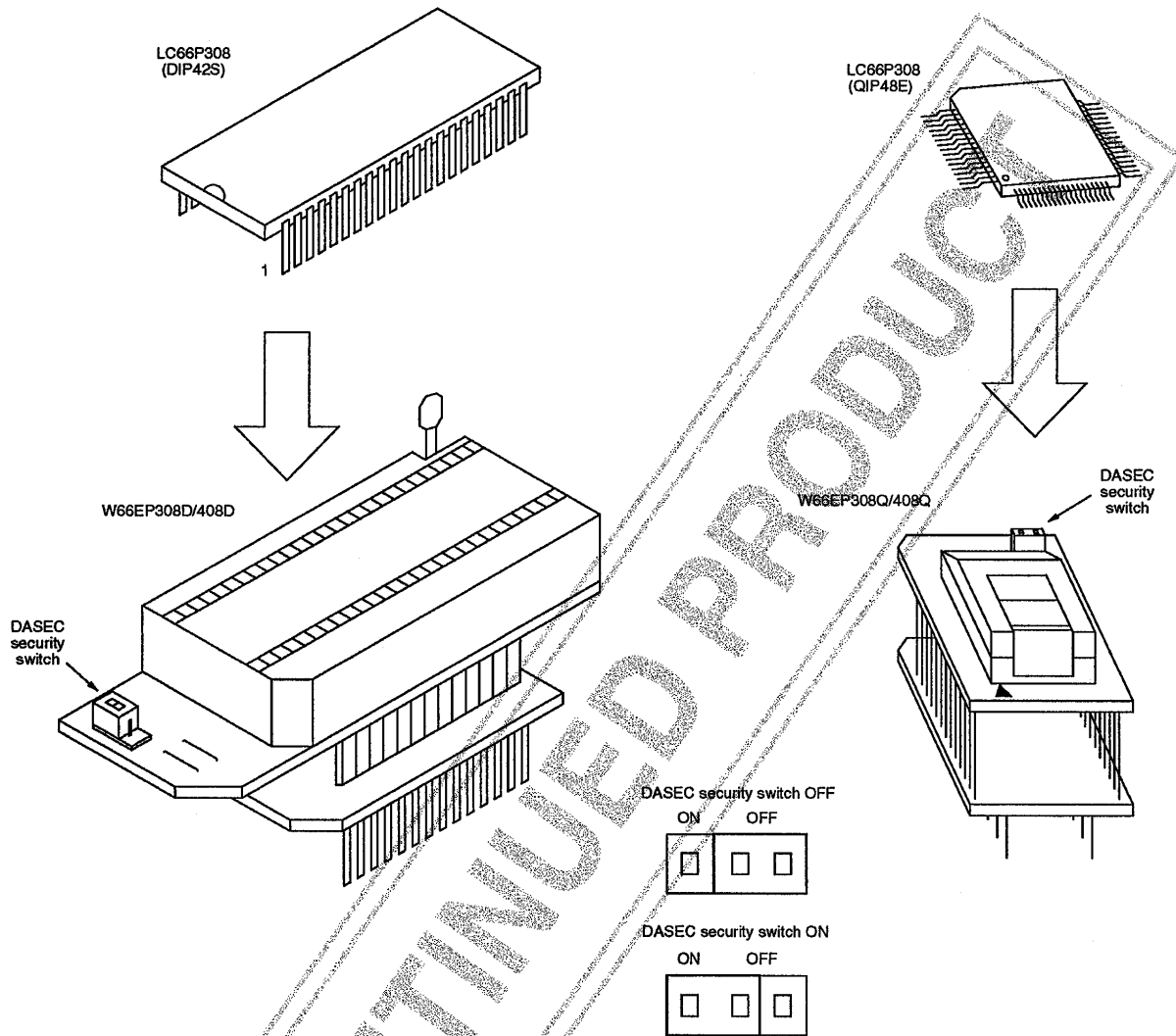
The assembler execute command when specifying programs and options using a SANYO cross assembler is LC66S.EXE.

# LC66P308

## PROM Programming

The PROM can be programmed using a special adapter board, W66EP308D/408D for the 42-pin DIP and

W66EP308Q/408Q for the 48-pin QIP as shown in the following figure, and a universal EPROM programmer.



Program the LC66P308 using the M mode of the PV command of the EVA800 or EVA850. The EPROM programmer should be Intel 27128 compatible with  $V_{PP} = 21$  V. The recommended programmers are shown in the following table. Please contact your nearest SANYO representative if you intend to use an alternative EPROM programmer.

Manufacturer	Model
ADVANTEST	TR4943, R4944A, R4945 or equivalent
SANYO	EVA850 or EVA800 special-purpose Programmers

### Notes

1. Intel is a registered trademark of Intel Corporation.
2. ADVANTEST is a registered trademark of ADVANTEST Corporation.

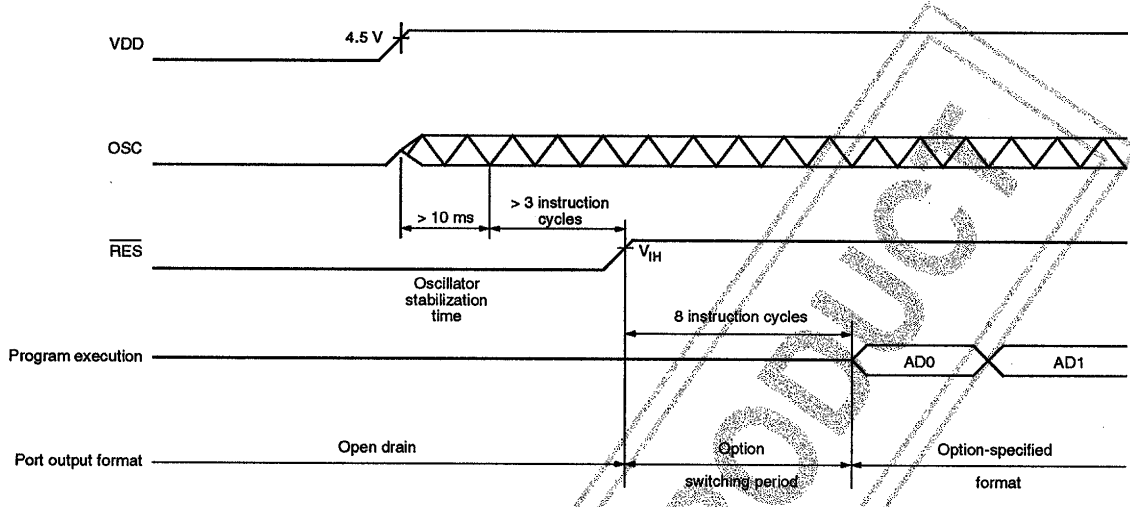
The EPROM programmer adapter incorporates a data security switch. When this switch is ON, data is secure, and when OFF, the data lines are floating and the PROM can be programmed. Note that when the data lines are floating, the EPROM programmer will return an error. This error can be ignored.

**Application Notes**

**Reset Timing**

The reset signal on  $\overline{\text{RES}}$  should be held LOW for a minimum of three instruction cycles after the oscillator has

stabilized to ensure correct operation, as shown in the following figure.



After a reset occurs, all I/O ports are reset to open-drain output configuration with floating outputs, except for ports P0 and P1 which both have an output level after reset option. The output configuration of each port is then set using the specified options during the eight instruction cycles after  $\overline{\text{RES}}$  goes HIGH. Program execution then begins from address 0000H.

The LC66E308/P308 can be reset while in hold mode ( $\text{HOLD/P33}$  is LOW). When  $\overline{\text{RES}}$  goes LOW in hold mode,  $\text{HOLD/P33}$  must go HIGH before  $\overline{\text{RES}}$  goes HIGH again.

**Reference Clock**

The external circuit for a ceramic resonator is shown in figure 6, and the recommended resonator and component values, in the following table. The oscillator stabilization characteristics are shown in figure 7.

Ceramic resonator	Capacitance	
	C1	C2
4 MHz Murata CSA -4.00MG	33 pF ±10%	33 pF ±10%
4 MHz Kyocera KBR -4.0MS	33 pF ±10%	33 pF ±10%
4 MHz Murata CST -4.00MG with internal capacitor	N/A	N/A
4 MHz Kyocera KBR -4.0MES with internal capacitor	N/A	N/A

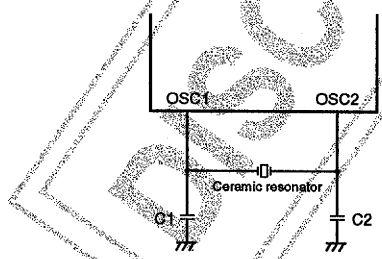


Figure 6. Ceramic resonator

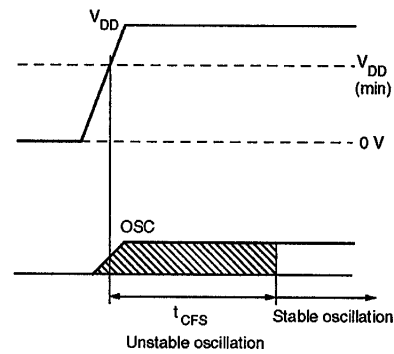
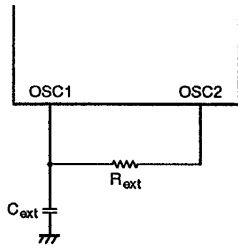


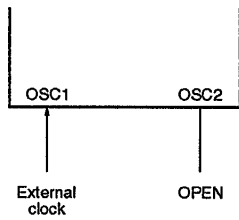
Figure 7. Ceramic resonator stabilization time

# LC66P308

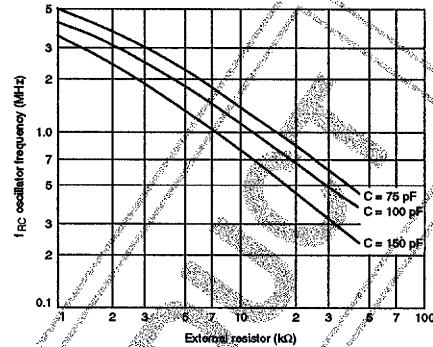
The external circuit for an RC oscillator is shown in the following figure.



The external clock input connection is OSC1. The remaining oscillator connection, OSC2, should be left open as shown in the following figure.



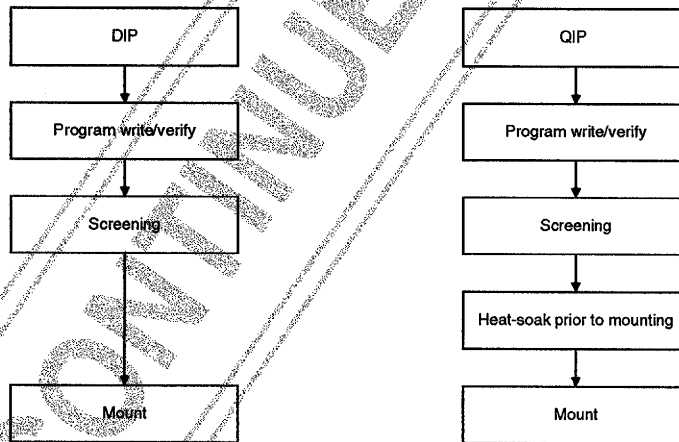
The RC oscillator frequency is determined by the external resistor and capacitor and has only been specified for  $R_{ext} = 2.2 \text{ k}\Omega$  and  $C_{ext} = 100 \text{ pF}$ . The frequency for other values of  $R_{ext}$  and  $C_{ext}$  can be determined from the graph in the following figure.



## Preparation Procedure

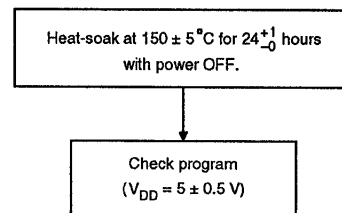
The preparation procedures shown in the following figure for DIP and QIP packages should always be followed prior to mounting the packages on the substrate. Note that

the QIP package should be heat-soaked for 24 hours at  $125 \text{ }^\circ\text{C}$  immediately prior to mounting.



## Screening procedure

The construction of the microcontroller with a blank built-in PROM makes it impossible for SANYO to completely factory-test it before shipping. To prove reliability of the programmed devices, the screening procedure shown in the following figure should always be followed.



Note that it is not possible to perform a write test on the blank PROM. 100% yield, therefore, cannot be guaranteed.

## LC66P308

### Ordering Information

When ordering identical mask ROM and PROM devices simultaneously, provide an EPROM containing the target memory contents together with separate order forms for each of the mask ROM and PROM versions.

When ordering a PROM device, provide an EPROM containing the target memory contents together with an order form. When ordering either an LC66354A 4 Kbyte or LC66356A 6 Kbyte mask ROM device, insert a jump command, or any similar command, to avoid executing an address beyond the range of the target device. In addition, write a 0 into all locations above 2007H.

A comparison of the LC66P308 characteristics with those of the LC663XX mask ROM devices is shown in the following table.

Parameter	Symbol	Condition	LC66P308	LC663XX series		Unit
				LC6630X series	LC66354A/6A/8A	
Supply voltage range	V <sub>DD</sub>	t <sub>CYC</sub> =0.92 to 10μs	4.5 to 5.5	4.0 to 6.0	—	V
		t <sub>CYC</sub> =3.92 to 10μs	—	—	2.2 to 5.5	
		t <sub>CYC</sub> =1.96 to 10μs	—	—	3.0 to 5.5	
Maximum halt-mode supply current	I <sub>DDHT</sub>	4MHz ceramic resonator	5.0	2.5	2.5	mA
		4MHz external clock	6.0	3.5	3.5	
		3MHz (typ) RC oscillators	5.0	2.5	—	
Hold-mode release hardware delay	N <sub>HOLD</sub>		65,536	65,536	16,384	Cycles
Hold-mode release time	t <sub>HOLD</sub>	f <sub>OSC</sub> =4MHz (t <sub>CYC</sub> =1μs)	≈ 64	≈ 64	—	ms
		f <sub>OSC</sub> =2MHz (t <sub>CYC</sub> =2μs)	—	—	≈ 32	
		f <sub>OSC</sub> =1MHz (t <sub>CYC</sub> =4μs)	—	—	≈ 64	
External RC oscillator capacitance	C <sub>ext</sub>		100	100	—	pF
External RC oscillator resistance	R <sub>ext</sub>		2.2	2.7	—	kΩ
Timer 0 contents after reset or hold-mode release			FF0	FF0	FFC	Hex
Port output configuration after reset			See note.	Specified by user option	Specified by user option	

### Note

Ports P2 to P6 and PC are open-drain and floating. Ports P0 and P1 have pull-up resistances and are HIGH or LOW.

A breakdown of the LC66 series devices, which includes the LC66308 and LC663XX devices, is shown in the following table.

Device	Pins	ROM capacity	RAM capacity	Package type
LC66304A/306A/308A	42/48	4/6/8 Kbyte ROM	512 bytes	DIP42S or QIP48E
LC66354A/356A/358A	42/48	4/6/8 Kbyte ROM	512 bytes	DIP42S or QIP48E
LC6635S <sup>∇</sup> /356S <sup>∇</sup> /358S <sup>∇</sup>	44	4/6/8 Kbyte ROM	512 bytes	QIP44M
LC66 E308	42/48	8 Kbyte EPROM	512 bytes	DIP42S or QIP48E
LC66 P308	42/48	8 Kbyte PROM	512 bytes	DIP42S or QIP48E
LC66404A/406A/408A	42/48	4/6/8 Kbyte ROM	512 bytes	DIP42S or QIP48E
LC66 E408	42/48	8 Kbyte EPROM	512 bytes	DIP42S or QIP48E
LC66 P408	42/48	8 Kbyte PROM	512 bytes	DIP42S or QIP48E
LC66506B/508B/512B/516B	64	6/8/12/16 Kbyte ROM	512 bytes	DIP64S or QIP64A
LC66556A/558A/562A/566A	64	6/8/12/16 Kbyte ROM	512 bytes	DIP64S or QIP64E
LC66E516	64	16 Kbyte EPROM	512 bytes	DIP64S or QIP64E
LC66P516	64	16 Kbyte PROM	512 bytes	DIP64S or QIP64E

### Note

∇ = under development

### SANYO ROM Services

SANYO offers various services at nominal charges. These include ROM writing, ROM reading, and package stamping and screening. Contact your local SANYO representative for further information.

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